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National Semiconductor

December 2000

LP2989

Micropower/Low Noise, 500 mA Ultra Low-Dropout Regulator

For Use with Ceramic Output Capacitors

General Description

The LP2989 is a fixed-output 500 mA precision LDO regulator designed for use with ceramic output capacitors.

Output noise can be reduced to 18µV (typical) by connecting an external 10 nF capacitor to the bypass pin.

Using an optimized VIP™ (Vertically Integrated PNP) process, the LP2989 delivers superior performance:

Dropout Voltage: Typically 310 mV @ 500 mA load, and 1 mV @ 100 μA load.

Ground Pin Current: Typically 3 mA @ 500 mA load, and 110 µA @ 100 µA load.

Sleep Mode: The LP2989 draws less than 0.8 μA quiescent current when shutdown pin is pulled low.

Error Flag: The built-in error flag goes low when the output drops approximately 5% below nominal.

Precision Output: Guaranteed output voltage accuracy is 0.75% ("A" grade) and 1.25% (standard grade) at room temperature.

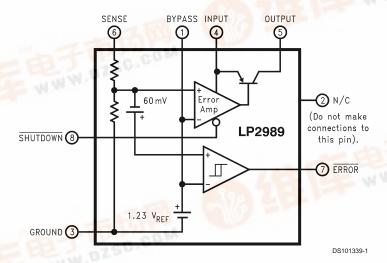
Features

- Ultra low dropout voltage
- Guaranteed 500 mA continuous output current
- Very low output noise with external capacitor
- SO-8, Mini SO-8, 8 Lead LLP surface mount packages
- <0.8 µA quiescent current when shutdown
- Low ground pin current at all loads
- 0.75% output voltage accuracy ("A" grade)
- High peak current capability (800 mA typical)
- Wide supply voltage range (16V max)
- Overtemperature/overcurrent protection
- -40°C to +125°C junction temperature range

Applications

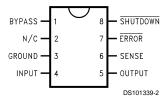
- Notebook/Desktop PC
- PDA/Palmtop Computer
- Wireless Communication Terminals
- SMPS Post-Regulator

Block Diagram



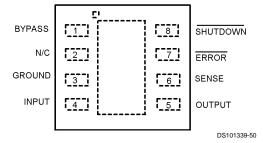
Connection Diagrams

Surface Mount Packages:



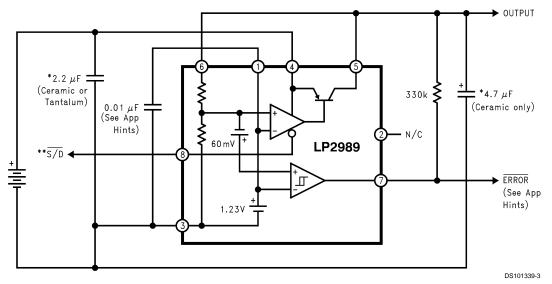
SO-8/Mini SO-8 Package See NS Package Drawing Numbers M08A/MUA08A

8 Lead LLP Surface Mount Package



Top View
See NS Package Number LDC08A

Basic Application Circuit



^{*}Capacitance values shown are minimum required to assure stability, but may be increased without limit. Larger output capacitor provides improved dynamic response. See Application Hints.

^{**}Shutdown must be actively terminated (see App. Hints). Tie to INPUT (Pin4) if not used

Ordering Information

TABLE 1. Package Marking and Ordering Information

Output Voltage	Grade Order Information		Package Marking	Supplied as:		
Lead LLP		T				
2.5	A	LP2989AILD-2.5	L01FA	1000 Units on Tape and Ree		
2.5	A	LP2989AILDX-2.5	L01FA	4500 Units on Tape and Ree		
2.5	STD	LP2989ILD-2.5	L01FB 1000 Units on Tap			
2.5	STD	LP2989ILDX-2.5	L01FB	4500 Units on Tape and Ree		
2.8	А	LP2989AILD-2.8	L000A	1000 Units on Tape and Ree		
2.8	А	LP2989AILDX-2.8	L000A	4500 Units on Tape and Ree		
2.8	STD	LP2989ILD-2.8	L000B	1000 Units on Tape and Ree		
2.8	STD	LP2989ILDX-2.8	L000B	4500 Units on Tape and Ree		
3.0	А	LP2989AILD-3.0	L01HA	1000 Units on Tape and Ree		
3.0	А	LP2989AILDX-3.0	L01HA	4500 Units on Tape and Ree		
3.0	STD	LP2989ILD-3.0	L01HB	1000 Units on Tape and Ree		
3.0	STD	LP2989ILDX-3.0	L01HB	4500 Units on Tape and Ree		
3.3	А	LP2989AILD-3.3	L01JA	1000 Units on Tape and Ree		
3.3	А	LP2989AILDX-3.3	L01JA	4500 Units on Tape and Ree		
3.3	STD	LP2989ILD-3.3	L01JB	1000 Units on Tape and Ree		
3.3	STD	LP2989ILDX-3.3	L01JB	4500 Units on Tape and Ree		
4.0	А	LP2989AILD-4.0	L01LA	1000 Units on Tape and Ree		
4.0	А	LP2989AILDX-4.0	L01LA	4500 Units on Tape and Ree		
4.0	STD	LP2989ILD-4.0	L01LB	1000 Units on Tape and Ree		
4.0	STD	LP2989ILDX-4.0	L01LB	4500 Units on Tape and Ree		
5.0	А	LP2989AILD-5.0	L01KA	1000 Units on Tape and Ree		
5.0	А	LP2989AILDX-5.0	L01KA	4500 Units on Tape and Ree		
5.0	STD	LP2989ILD-5.0	L01KB	1000 Units on Tape and Ree		
5.0	STD	LP2989ILDX-5.0	L01KB	4500 Units on Tape and Ree		
Lead MSOP (MM)					
2.5	А	LP2989AIMM-2.5	LA0A	1000 Units on Tape and Ree		
2.5	А	LP2989AIMMX-2.5	LA0A	3500 Units on Tape and Ree		
2.5	STD	LP2989IMM-2.5	LA0B	1000 Units on Tape and Ree		
2.5	STD	LP2989IMMX-2.5	LA0B	3500 Units on Tape and Ree		
2.8	А	LP2989AIMM-2.8	LA6A	1000 Units on Tape and Ree		
2.8	А	LP2989AIMMX-2.8	LA6A	3500 Units on Tape and Ree		
2.8	STD	LP2989IMM-2.8	LA6B	1000 Units on Tape and Ree		
2.8	STD	LP2989IMMX-2.8	LA6B	3500 Units on Tape and Ree		
3.0	А	LP2989AIMM-3.0	LA1A	1000 Units on Tape and R		
3.0	А	LP2989AIMMX-3.0	LA1A	3500 Units on Tape and Ree		
3.0	STD	LP2989IMM-3.0	LA1B	1000 Units on Tape and Re		
3.0	STD	LP2989IMMX-3.0	LA1B	3500 Units on Tape and Ree		
3.3	А	LP2989AIMM-3.3	LA2A	1000 Units on Tape and Re		
3.3	А	LP2989AIMMX-3.3	LA2A	3500 Units on Tape and Ree		
3.3	STD	LP2989IMM-3.3	LA2B	1000 Units on Tape and Ree		
3.3	STD	LP2989IMMX-3.3	LA2B	3500 Units on Tape and Ree		
5.0	А	LP2989AIMM-5.0	LA4A	1000 Units on Tape and Rec		
5.0	А	LP2989AIMMX-5.0	LA4A	3500 Units on Tape and Ree		
5.0	STD	LP2989IMM-5.0	LA4B	1000 Units on Tape and Rec		
5.0	STD	LP2989IMMX-5.0	LA4B	3500 Units on Tape and Rec		

Ordering Information (Continued)

TABLE 1. Package Marking and Ordering Information (Continued)

Output Voltage	Grade	Order Information	Package Marking	Supplied as:	
SO-8 (M)					
2.5	А	LP2989AIMX-2.5	LP2989AIM2.5	2500 Units on Tape and Reel	
2.5	A	LP2989AIM-2.5	LP2989AIM2.5	Shipped in Anti-Static Rails	
2.5	STD	LP2989IMX-2.5	LP2989IM2.5	2500 Units on Tape and Reel	
2.5	STD	LP2989IM-2.5	LP2989IM2.5	Shipped in Anti-Static Rails	
3.3	А	LP2989AIMX-3.3	LP2989AIM3.3	2500 Units on Tape and Reel	
3.3	А	LP2989AIM-3.3	LP2989AIM3.3	Shipped in Anti-Static Rails	
3.3	STD	LP2989IMX-3.3	LP2989IM3.3	2500 Units on Tape and Reel	
3.3	STD	LP2989IM-3.3	LP2989IM3.3	Shipped in Anti-Static Rails	
5.0	А	LP2989AIMX-5.0	LP2989AIM5.0	2500 Units on Tape and Reel	
5.0	А	LP2989AIM-5.0	LP2989AIM5.0	Shipped in Anti-Static Rails	
5.0	STD	LP2989IMX-5.0	LP2989IM5.0	2500 Units on Tape and Reel	
5.0	STD	LP2989IM-5.0	LP2989IM5.0	Shipped in Anti-Static Rails	

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range -65°C to +150°C

Operating

Junction Temperature Range -40°C to +125°C

Lead Temperature (Soldering,

5 seconds)

ESD Rating (Note 2) 2 kV Internally Limited

Power Dissipation (Note 3)

Input Supply Voltage (Survival) -0.3V to +16V

Input Supply Voltage

(Operating) 2.1V to +16V Sense Pin -0.3V to +6V

Output Voltage (Survival)

(Note 4) -0.3V to +16VShort Circuit

I_{OUT} (Survival)

Protected

Input-Output Voltage (Survival)

(Note 5) -0.3V to +16V

Electrical Characteristics

Limits in standard typeface are for $T_J = 25$ °C, and limits in **boldface type** apply over the full operating temperature range. Unless otherwise specified: V_{IN} = $V_{O}(NOM)$ + 1V, I_{L} = 1 mA, C_{OUT} = 4.7 μ F, C_{IN} = 2.2 μ F, $V_{S/D}$ = 2V.

260°C

Symbol	Parameter	Conditions	Typical	LP2989AI-X.X (Note 6)		LP2989I-X.X (Note 6)		Units
				Min	Max	Min	Max	
V _O	Output Voltage			-0.75	0.75	-1.25	1.25	
	Tolerance	1 mA < I_L < 500 mA $V_O(NOM) + 1V \le V_{IN} \le$		-1.5	1.5	-2.5	2.5	
		$V_{O}(NOM) + 1V \le V_{IN} \le 16V$		-4.0	2.5	-5.0	3.5	%V _{NOM}
		1 mA < I_L < 500 mA $V_O(NOM)$ + 1V $\leq V_{IN} \leq$ 16V $-25^{\circ}C \leq T_J \leq 125^{\circ}C$		-3.5	2.5	-4.5	3.5	- 70 V NOM
Δ٧0	Output Voltage Line	$V_{O}(NOM) + 1V \le V_{IN} \le$			0.014		0.014	
$\frac{1}{\Delta V_{1N}}$	Regulation	16V	0.005		0.032		0.032	
$\frac{\Delta V_0}{\Delta I_L}$	Load Regulation	1 mA < I _L < 500 mA	0.4					%V _{NOM}
V _{IN} –V _O	Dropout Voltage	Ι _L = 100 μΑ	1		3		3	mV
	(Note 7)				4		4	
		I _L = 200 mA	450		200		200	
			150		300		300	
		I _L = 500 mA	310		425		425	
					650		650	
I _{GND}	Ground Pin Current	Ι _L = 100 μΑ	110		175		175	μА
					200		200	
		I _L = 200 mA	1		2		2	
			1		3.5		3.5	mA
		I _L = 500 mA	3		6		6	
					9		9	
		V _{S/D} < 0.18V	0.5		2		2	μA
		V _{S/D} < 0.4V	0.05		8.0		0.8	μΛ
I _O (PK)	Peak Output Current	$V_{OUT} \ge V_{O}(NOM) - 5\%$	800	600		600		mA
I _O (MAX)	Short Circuit Current	R _L = 0 (Steady State) (Note 9)	1000					
e _n	Output Noise Voltage (RMS)	BW = 100 Hz to 100 kHz, C_{OUT} = 10 μ F C_{BYPASS} = .01 μ F V_{OUT} = 2.5V	18					μV(RMS
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Ripple Rejection	f = 1 kHz, C _{OUT} = 10 μF	60					dB

Electrical Characteristics (Continued)

Limits in standard typeface are for $T_J = 25^{\circ}C$, and limits in **boldface type** apply over the full operating temperature range. Unless otherwise specified: $V_{IN} = V_O(NOM) + 1V$, $I_L = 1$ mA, $C_{OUT} = 4.7$ µF, $C_{IN} = 2.2$ µF, $V_{S/D} = 2V$.

Symbol	Parameter	Conditions	Typical	LP2989AI-X.X (Note 6)		LP2989I-X.X (Note 6)		Units
				Min	Max	Min	Max	
$\frac{\Delta V_{OUT}}{\Delta T}$	Output Voltage Temperature Coefficient	(Note 8)	20					ppm/°C
SHUTDOWN	NINPUT			•				•
V _{S/D} S/E	S/D Input Voltage	V _H = O/P ON	1.4	1.6		1.6		V
		$V_L = O/P OFF$ $I_{IN} \le 2 \mu A$	0.50		0.18		0.18	
I _{S/D}	S/D Input Current	$V_{S/D} = 0$	0.001		-1		-1	μА
		$V_{S/D} = 5V$	5		15		15	
ERROR CO	MPARATOR			•				•
Гон	Output "HIGH" Leakage	V _{OH} = 16V	0.001		1		1	μА
					2		2	
V _{OL}	Output "LOW" Voltage	$V_{IN} = V_{O}(NOM) - 0.5V,$ $I_{O}(COMP) = 150 \mu A$	150		220		220	mV
					350		350	
V_{THR}	Upper Threshold		-4.8	-6.0	-3.5	-6.0	-3.5	%V _{OUT}
(MAX)	Voltage		-4.0	-8.3	-2.5	-8.3	-2.5	
V _{THR}	Lower Threshold		-6.6	-8.9	-4.9	-8.9	-4.9	
(MIN)	Voltage			-13.0	-3.0	-13.0	-3.0	
HYST	Hysteresis		2.0]

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its rated operating conditions.

Note 2: ESD testing was performed using Human Body Model, a 100 pF capacitor discharged through a 1.5 k Ω resistor.

Note 3: The maximum allowable power dissipation is a function of the maximum junction temperature, $T_J(MAX)$, the junction-to-ambient thermal resistance, θ_{J-A} , and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using:

$$P(MAX) = \frac{T_{J}(MAX) - T_{A}}{\theta_{J-A}}$$

The value of θ_{J-A} for the SO-8 (M) package is 160°C/W and the mini SO-8 (MM) package is 200°C/W. The value θ_{J-A} for the LLP (LD) package is specifically dependent on PCB trace area, trace material, and the number of layers and thermal vias. For improved thermal resistance and power dissipation for the LLP package, refer to Application Note AN-1187. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown.

Note 4: If used in a dual-supply system where the regulator load is returned to a negative supply, the LP2989 output must be diode-clamped to ground.

Note 5: The output PNP structure contains a diode between the V_{IN} and V_{OUT} terminals that is normally reverse-biased. Forcing the output above the input will turn on this diode and may induce a latch-up mode which can damage the part (see Application Hints).

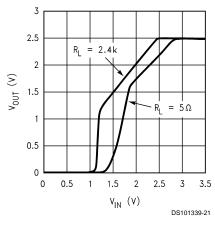
Note 6: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate National's Average Outgoing Quality Level (AOQL).

Note 7: Dropout voltage is defined as the input to output differential at which the output voltage drops 100 mV below the value measured with a 1V differential.

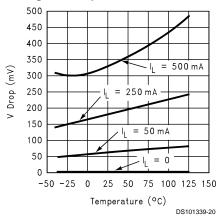
Note 8: Temperature coefficient is defined as the maximum (worst-case) change divided by the total temperature range.

Note 9: See Typical Performance Characteristics curves.

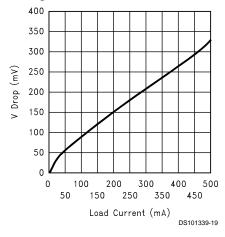
Dropout Characteristics



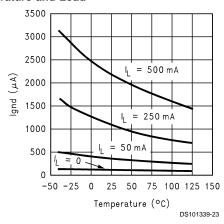
Dropout Voltage vs Temperature



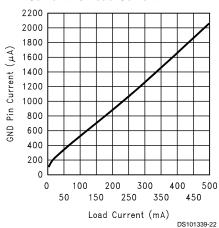
Dropout Voltage vs Load Current



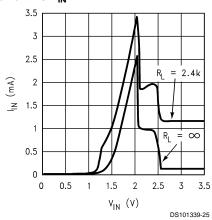
GND Pin Current vs Temperature and Load



Ground Pin Current vs Load Current

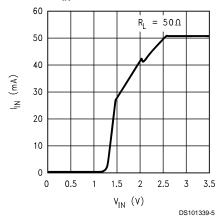


Input Current vs V_{IN}

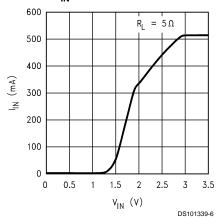


 $\begin{tabular}{ll} \textbf{Typical Performance Characteristics} & \textbf{Unless otherwise specified:} & \textbf{T}_{A} = 25^{\circ}\textbf{C}, & \textbf{C}_{OUT} = 4.7 \ \mu \textbf{F}, \\ \textbf{C}_{IN} = 2.2 \ \mu \textbf{F}, & \textbf{S/D} & \textbf{is tied to V}_{IN}, & \textbf{V}_{IN} = \textbf{V}_{O}(NOM) + 1 \textbf{V}, & \textbf{I}_{L} = 1 \ mA, & \textbf{V}_{OUT} = 2.5 \textbf{V}. \\ \end{tabular}$

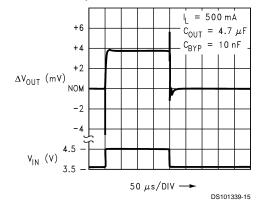
Input Current vs V_{IN}



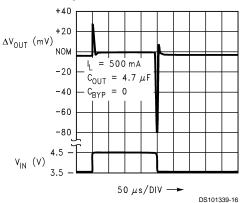
Input Current vs V_{IN}



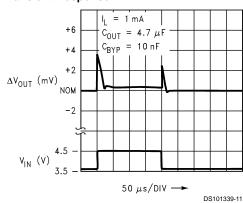
Line Transient Response



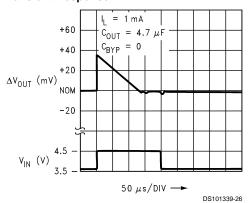
Line Transient Response



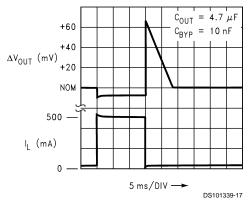
Line Transient Response



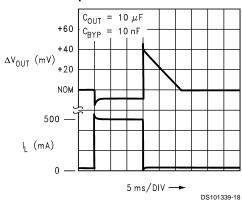
Line Transient Response



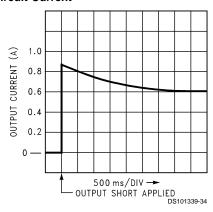
Load Transient Response



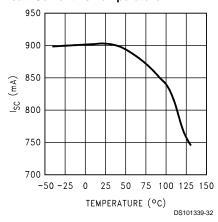
Load Transient Response



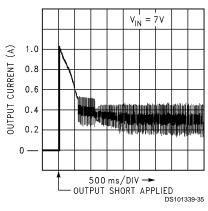
Short Circuit Current



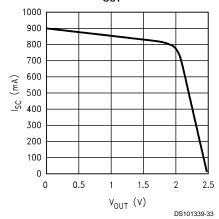
Short Circuit Current vs Temperature



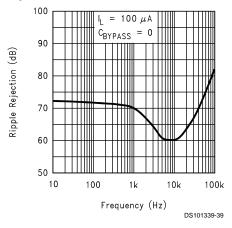
Short Circuit Current



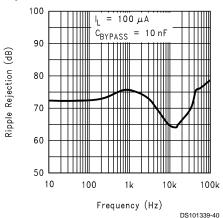
Short Circuit Current vs Vout



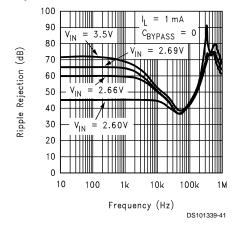
Ripple Rejection



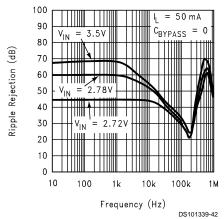
Ripple Rejection



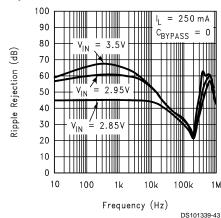
Ripple Rejection



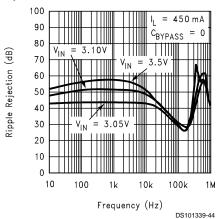
Ripple Rejection



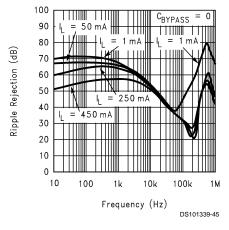
Ripple Rejection



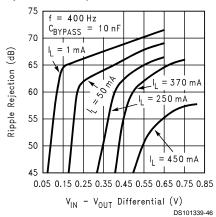
Ripple Rejection



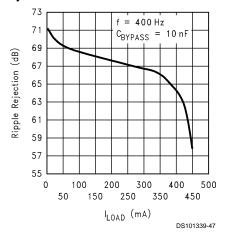
Ripple Rejection



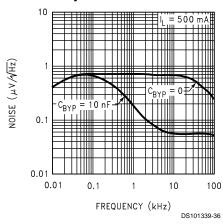
Ripple Rejection In Dropout



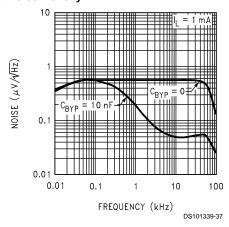
Ripple Rejection vs Load



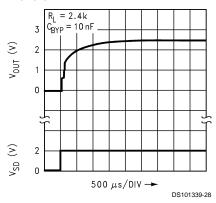
Output Noise Density



Output Noise Density

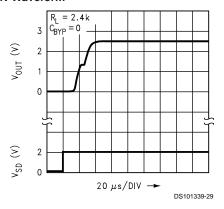


Turn-ON Waveform

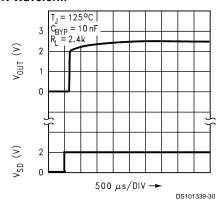


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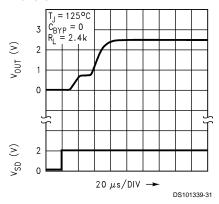
Turn-ON Waveform



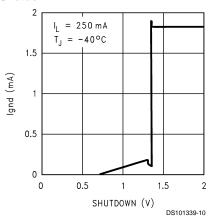
Turn-ON Waveform



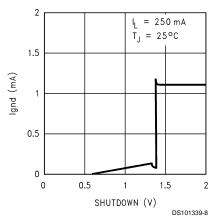
Turn-ON Waveform



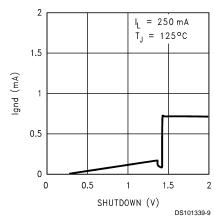
 I_{GND} vs Shutdown



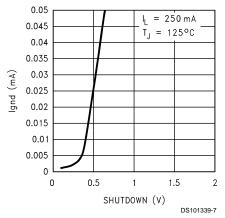
$I_{\rm GND}$ vs Shutdown



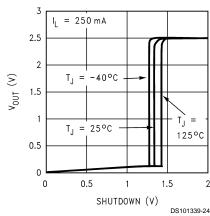
 $I_{\rm GND}$ vs Shutdown



I_{GND} vs Shutdown



V_{OUT} vs Shutdown



Application Hints

LLP Package Devices

The LP2989 is offered in the 8 lead LLP surface mount package to allow for increased power dissipation compared to the SO-8 and Mini SO-8. For details on thermal performance as well as mounting and soldering specifications, refer to Application Note AN-1187.

EXTERNAL CAPACITORS

Like any low-dropout regulator, the LP2989 requires external capacitors for regulator stability. These capacitors must be correctly selected for good performance.

INPUT CAPACITOR: An input capacitor whose size is at least 2.2 μ F is required between the LP2989 input and ground (the amount of capacitance may be increased without limit).

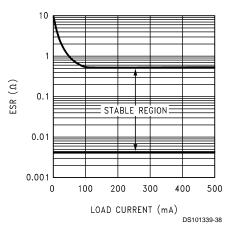
Characterization testing performed on the LP2989 has shown that if the amount of actual input capacitance drops below about 1.5 μ F, an unstable operating condition may result. Therefore, the next larger standard size (2.2 μ F) is specified as the minimum required input capacitance. Capacitor tolerance and temperature variation must be considered when selecting a capacitor (see **Capacitor Characteristics** section) to assure the minimum requirement of 1.5 μ F is met over all operating conditions.

The input capacitor must be located at a distance of not more than 0.5" from the input pin and returned to a clean analog ground. Any good quality ceramic or tantalum may be used for this capacitor, assuming the minimum capacitance requirement is met.

OUTPUT CAPACITOR: The LP2989 requires a ceramic output capacitor whose size is at least 4.7µF. The actual amount of capacitance on the output must never drop below about 3.5µF or unstable operation may result. For this reason, capacitance tolerance and temperature characteristics must be considered when selecting an output capacitor.

The LP2989 is designed specifically to work with ceramic output capacitors, utilizing circuitry which allows the regulator to be stable across the entire range of output current with an output capacitor whose ESR is as low as 4 m Ω . It may also be possible to use Tantalum or film capacitors at the output, but these are not as attractive for reasons of size and cost (see next section Capacitor Characteristics).

The output capacitor must meet the requirement for minimum amount of capacitance and also have an ESR (equivalent series resistance) value which is within the stable range. Curves are provided which show the stable ESR range as a function of load current (see ESR graph below).



Stable Region For output Capacitor ESR

Important: The output capacitor must maintain its ESR within the stable region *over the full operating temperature range of the application* to assure stability.

It is important to remember that capacitor tolerance and variation with temperature must be taken into consideration when selecting an output capacitor so that the minimum required amount of output capacitance is provided over the full operating temperature range. (See Capacitor Characteristics section).

The output capacitor must be located not more than 0.5" from the output pin and returned to a clean analog ground.

NOISE BYPASS CAPACITOR: Connecting a 10 nF capacitor to the Bypass pin significantly reduces noise on the regulator output. However, the capacitor is connected directly to a high-impedance circuit in the bandgap reference.

Because this circuit has only a few microamperes flowing in it, any significant loading on this node will cause a change in the regulated output voltage. For this reason, DC leakage current through the noise bypass capacitor must never exceed 100 nA, and should be kept as low as possible for best output voltage accuracy.

The types of capacitors best suited for the noise bypass capacitor are ceramic and film. High-quality ceramic capacitors with either NPO or COG dielectric typically have very low leakage. 10 nF polypropolene and polycarbonate film capacitors are available in small surface-mount packages and typically have extremely low leakage current.

CAPACITOR CHARACTERISTICS

CERAMIC: The LP2989 was designed to work with ceramic capacitors on the output to take advantage of the benefits they offer: for capacitance values in the 4.7 μ F range, ceramics are the least expensive and also have the lowest ESR values (which makes them best for eliminating high-frequency noise). The ESR of a typical 4.7 μ F ceramic capacitor is in the range of 10 m Ω to 15 m Ω , which easily meets the ESR limits required for stability by the LP2989.

One disadvantage of ceramic capacitors is that their capacitance can vary with temperature. Many large value ceramic capacitors ($\geq 2.2~\mu F$) are manufactured with the Z5U or Y5V temperature characteristic, which results in the capacitance dropping by more than 50% as the temperature goes from 25°C to 85°C.

This could cause problems if a 4.7 μ F capacitor were used on the output since it will drop down to approximately 2.4 μ F at high ambient temperatures (which could cause the LP2989 to oscillate). Another significant problem with Z5U

Application Hints (Continued)

and Y5V dielectric devices is that the capacitance drops severely with applied voltage. A typical Z5U or Y5V capacitor can lose 60% of its rated capacitance with half of the rated voltage applied to it.

For these reasons, X7R and X5R type ceramic capacitors must be used on the input and output of the LP2989.

TANTALUM: Tantalum capacitors are less desirable than ceramics for use as output capacitors because they are typically more expensive when comparing equivalent capacitance and voltage ratings in the 1 μF to 4.7 μF range.

Another important consideration is that Tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a Tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value

It should also be noted that the ESR of a typical Tantalum will increase about 2:1 as the temperature goes from 25°C down to -40°C, so some guard band must be allowed.

Tantalum capacitors may be used on the input as long as the requirement for minimum capacitance is met.

FILM: Polycarbonate and polypropelene film capacitors have excellent electrical performance: their ESR is the lowest of the three types listed, their capacitance is very stable with temperature, and DC leakage currrent is extremely low.

One disadvantage is that film capacitors are larger in physical size than ceramic or tantalum which makes film a poor choice for either input or output capacitors.

However, their low leakage makes them a good choice for the noise bypass capacitor. Since the required amount of capacitance is only .01 μ F, small surface-mount film capacitors are available in this size.

SHUTDOWN INPUT OPERATION

The LP2989 is shut off by driving the Shutdown input low, and turned on by pulling it high. If this feature is not to be used, the Shutdown input should be tied to V_{IN} to keep the regulator output on at all times.

To assure proper operation, the signal source used to drive the Shutdown input must be able to swing above and below the specified turn-on/turn-off voltage thresholds listed in the Electrical Characteristics section under $V_{\text{ON/OFF}}$.

To prevent mis-operation, the turn-on (and turn-off) voltage signals applied to the Shutdown input must have a slew rate which is \geq 40 mV/ μ s.

CAUTION: the regulator output voltage can not be guaranteed if a slow-moving AC (or DC) signal is applied that is in the range between the specified turn-on and turn-off voltages listed under the electrical specification $V_{ON/OFF}$ (see Electrical Characteristics).

REVERSE INPUT-OUTPUT VOLTAGE

The PNP power transistor used as the pass element in the LP2989 has an inherent diode connected between the regulator output and input.

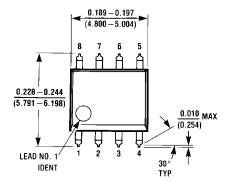
During normal operation (where the input voltage is higher than the output) this diode is reverse-biased.

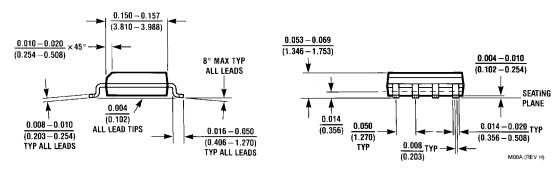
However, if the output is pulled above the input, this diode will turn ON and current will flow into the regulator output.

In such cases, a parasitic SCR can latch which will allow a high current to flow into V_{IN} (and out the ground pin), which can damage the part.

In any application where the output may be pulled above the input, an external Schottky diode must be connected from V_{IN} to V_{OUT} (cathode on V_{IN} , anode on V_{OUT}), to limit the reverse voltage across the LP2989 to 0.3V (see Absolute Maximum Ratings).

Physical Dimensions inches (millimeters) unless otherwise noted

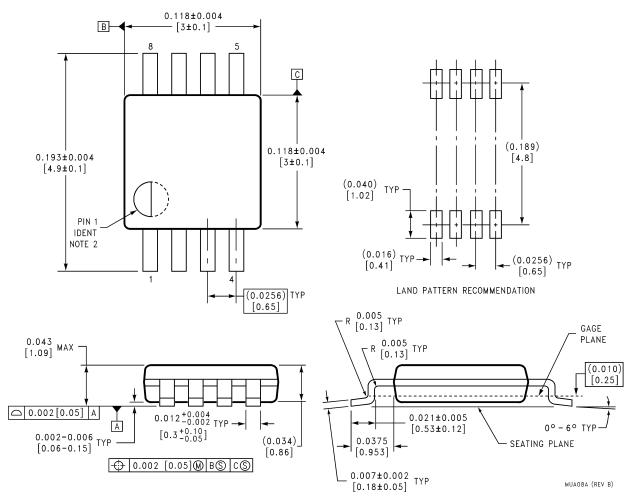




SO-8 Package NS Package Number M08A

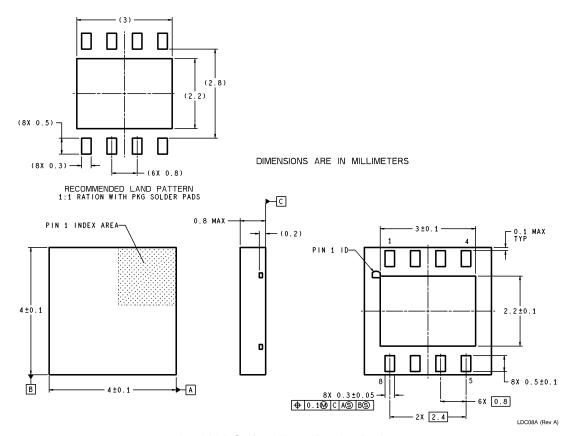
16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Mini SO-8 Package NS Package Number MUA08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



8 Lead LLP Surface Mount PackagePackage NS Package Number LDC08A

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